

2SC380 NPN Silicon Epitaxial Planar Transistor

High frequency amplifier application
for FM IF, OSC stage and AM CONV. IF stage

The transistor is subdivided into three groups R, O,
and Y, according to its DC current gain.



1. Emitter 2. Collector 3. Base
TO-92 Plastic Package
Weight approx. 0.19g

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

| Parameter | Symbol | Value | Unit |
|---------------------------|-----------|-------------|------|
| Collector Base Voltage | V_{CBO} | 35 | V |
| Collector Emitter Voltage | V_{CEO} | 30 | V |
| Emitter Base Voltage | V_{EBO} | 4 | V |
| Collector Current | I_C | 50 | mA |
| Emitter Current | $-I_E$ | 50 | mA |
| Power Dissipation | P_{tot} | 300 | mW |
| Junction Temperature | T_j | 125 | °C |
| Storage Temperature Range | T_s | -55 to +125 | °C |

Characteristics at $T_{amb} = 25^\circ\text{C}$

| Parameter | Symbol | Min. | Typ. | Max. | Unit |
|---|----------------|----------|------|------|---------------|
| DC Current Gain at $V_{CE} = 12 \text{ V}$, $I_C = 2 \text{ mA}$ | R | h_{FE} | 40 | - | 80 |
| | O | h_{FE} | 70 | - | 140 |
| | Y | h_{FE} | 120 | - | 240 |
| Collector Cutoff Current at $V_{CB} = 35 \text{ V}$ | I_{CBO} | - | - | 0.1 | μA |
| Emitter Cutoff Current at $V_{EB} = 4 \text{ V}$ | I_{EBO} | - | - | 0.1 | μA |
| Collector Emitter Saturation Voltage at $I_C = 10 \text{ mA}$, $I_B = 1 \text{ mA}$ | $V_{CE(sat)}$ | - | - | 0.4 | V |
| Base Emitter Saturation Voltage at $I_C = 10 \text{ mA}$, $I_B = 1 \text{ mA}$ | $V_{BE(sat)}$ | - | - | 1 | V |
| Transition Frequency at $V_{CE} = 10 \text{ V}$, $I_C = 1 \text{ mA}$ | f_T | 100 | - | 400 | MHz |
| Collector Output Capacitance at $V_{CB} = 10 \text{ V}$, $f = 1 \text{ MHz}$ | C_{ob} | 1.4 | 2 | 3.2 | pF |
| Collector Base Time Constant at $V_{CE} = 10 \text{ V}$, $-I_E = 1 \text{ mA}$, $f = 30 \text{ MHz}$ | $C_c, r_{bb'}$ | 10 | - | 50 | ps |
| Power Gain at $V_{CC} = 6 \text{ V}$, $f = 10.7 \text{ MHz}$, $-I_E = 1 \text{ mA}$ | G_{pe} | 27 | 29 | 33 | dB |

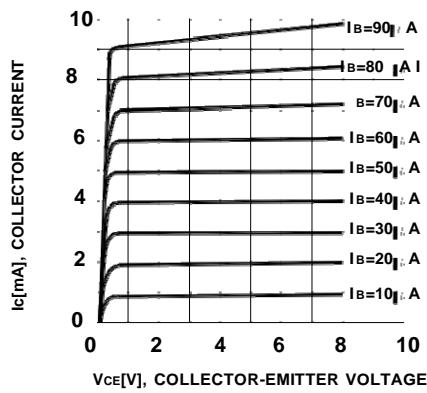


Figure 1. Static Characteristic

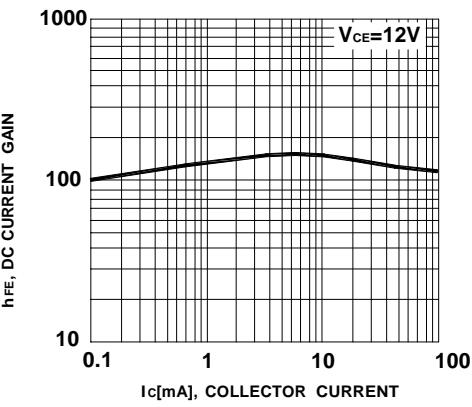


Figure 2. DC Current Gain

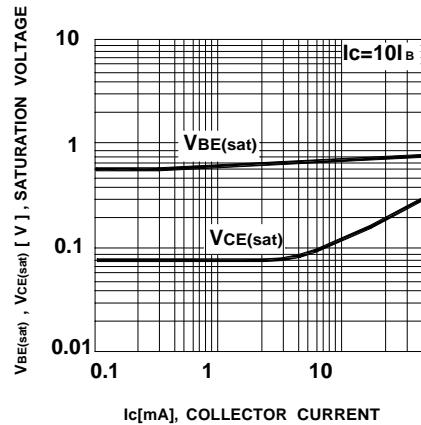


Figure 3. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

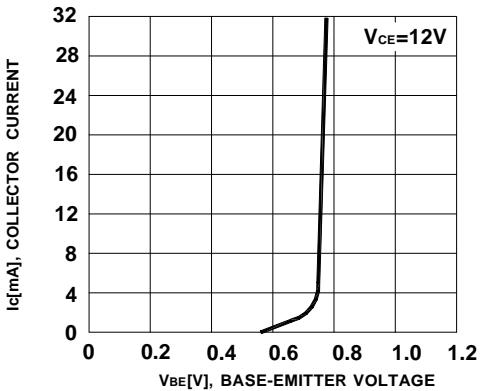


Figure 4. Base-Emitter On Voltage

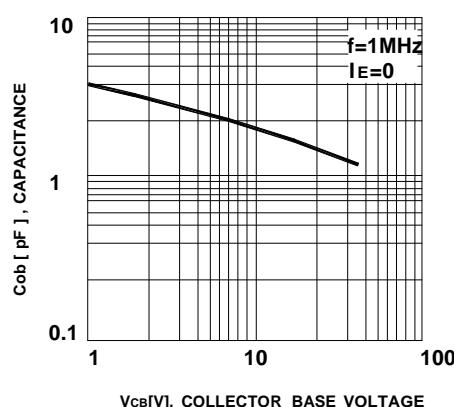


Figure 5. Collector Output Capacitance

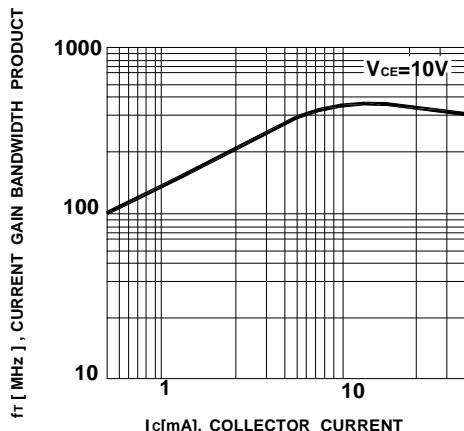


Figure 6. Current Gain Bandwidth Product